# LE A P2W

#### **OSRAM OSTAR® Projection Power**

OSRAM OSTAR Projection Power is a high luminance LED for projection applications.



### **Applications**

- Projection Home LED & Laser

- Projection Professional LED & Laser

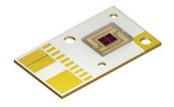
### **Features:**

- Package: OSTAR High Power Projection
- Chip technology: Thinfilm
- Typ. Radiation: 120° (Lambertian emitter)
- Color:  $\lambda_{dom} = 617 \text{ nm} (\bullet \text{ amber})$
- Corrosion Robustness Class: 3B
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

### **Ordering Information**

Туре	Luminous Flux <sup>1)</sup> $I_F = 24000 \text{ mA}$ $\Phi_V$	Ordering Code
LE A P2W-SUTR-23	2590 3590 lm	Q65112A7738





## **Maximum Ratings**

Parameter	Symbol		Values
Operating Temperature	T <sub>op</sub>	min.	-40 °C
	- 1	max.	100 °C
Storage Temperature	T <sub>stg</sub>	min.	-40 °C
		max.	100 °C
Junction Temperature	T <sub>j</sub>	max.	125 °C
Forward Current	I <sub>F</sub>	min.	400 mA
$T_J = 125 \text{ °C}$ ; all chips operated in parallel		max.	20000 mA
Forward Current pulsed D = 0.25 ; f = 240 Hz; $T_J$ = 25 °C; all chips operated in parallel	I <sub>F pulse</sub>		24000 mA
Surge Current tp $\leq$ 10 µs; D = 0.1; T <sub>J</sub> = 125 °C; all chips operated in parallel	I <sub>FS</sub>	max.	32000 mA
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	$V_{ESD}$		2 kV
Reverse current <sup>2)</sup>	I <sub>R</sub>	max.	200 mA



### **Characteristics**

 $T_{Board}$  = 25 °C;  $I_{F}$  = 24000 mA; f = 1000 Hz;  $t_{int}$  = 100 ms; D = 0.25; all chips operated in parallel

Parameter	Symbol		Values
Peak Wavelength	$\lambda_{_{peak}}$	typ.	624 nm
Dominant Wavelength <sup>3)</sup>	$\lambda_{dom}$	min. typ. max.	612 nm 617 nm 624 nm
Spectral bandwidth at 50% I <sub>rel,max</sub>	Δλ	typ.	18 nm
Viewing angle at 50% $\rm I_v$	2φ	typ.	120 °
Radiating surface	A <sub>color</sub>	typ.	2.6 x 3.2 mm <sup>2</sup>
Partial Flux acc. CIE 127:2007 <sup>4)</sup> I <sub>F</sub> = 24000 mA	$\Phi_{\rm E/V,\ 120^\circ}$	typ.	0.82
Forward Voltage <sup>5)</sup> $I_F = 24000 \text{ mA}$ ; all chips operated in parallel	V <sub>F</sub>	min. typ. max.	2.80 V 3.00 V 4.00 V
Deviation of forward voltage of all chips	V <sub>F</sub>	max.	135 mV
Reverse voltage (ESD device)	V <sub>r esd</sub>	min.	45 V
Reverse voltage <sup>2)</sup> I <sub>R</sub> = 20 mA	V <sub>R</sub>	max.	1.2 V
Real thermal resistance junction/board <sup>6)</sup>	$R_{thJBreal}$	typ. max.	0.6 0.7
Electrical thermal resistance junction/board $^{\rm 6)}$ with efficiency $\eta_{\rm e}$ = 13 %	$R_{thJB elec.}$	typ. max.	0.52 0.61



## **Brightness Groups**

Group	Luminous Flux <sup>1)</sup> $I_F = 24000 \text{ mA}$ min. $\Phi_V$	Luminous Flux <sup>1)</sup> I <sub>F</sub> = 24000 mA max. $\Phi_v$
SU	2590 lm	2800 lm
TP	2800 lm	3040 lm
TQ	3040 lm	3300 lm
TR	3300 lm	3590 lm

## Wavelength Groups

Group	Dominant Wavelength 3)	Dominant Wavelength <sup>3)</sup>
	min.	max.
	λ <sub>dom</sub>	$\lambda_{dom}$
2	612 nm	618 nm
3	618 nm	624 nm

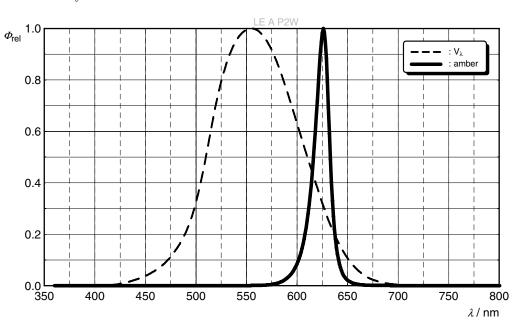
## Group Name on Label

Example: SU-2 Brightness	Wavelength
SU	2



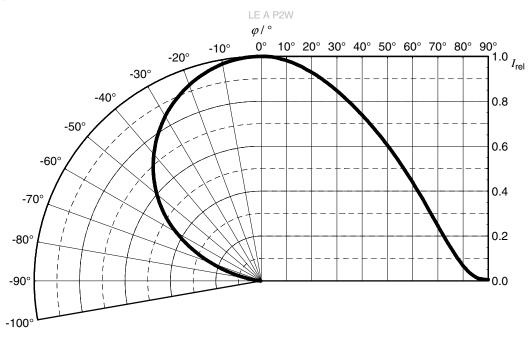
#### **Relative Spectral Emission**<sup>4)</sup>

 $\Phi_{_{rel}}$  = f (\lambda); I $_{_F}$  = 24000 mA; T $_{_J}$  = 25 °C; all chips operated in parallel



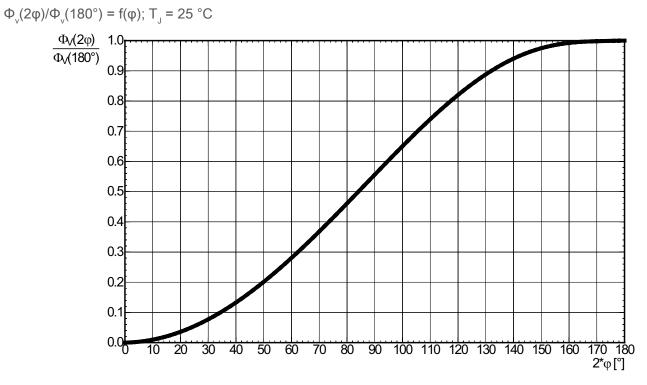
#### **Radiation Characteristics**<sup>4)</sup>

I<sub>rel</sub> = f (φ); T<sub>J</sub> = 25 °C





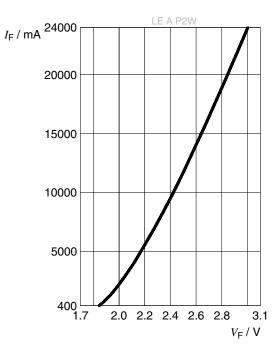
### **Relative Partial Flux**<sup>4)</sup>





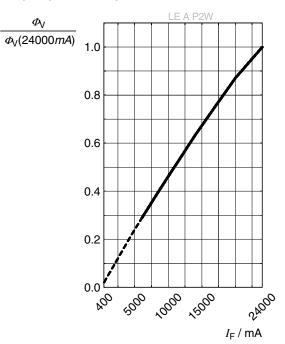
#### Forward current <sup>4), 7)</sup>

 $I_{_{F}} = f(V_{_{F}}); T_{_{J}} = 25 \text{ °C};$ all chips operated in parallel



### Relative Luminous Flux <sup>4), 7)</sup>

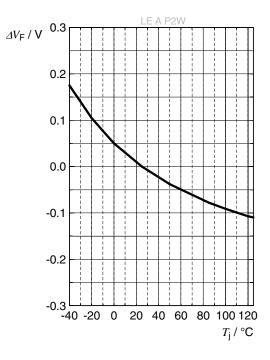
 $\Phi_v/\Phi_v(24000 \text{ mA}) = f(I_F); T_J = 25 \text{ °C};$ all chips operated in parallel





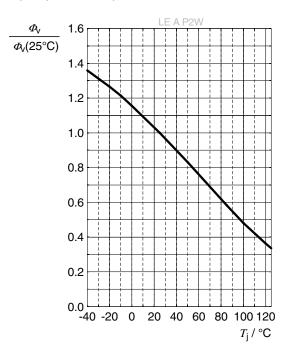
### Forward Voltage <sup>4)</sup>

 $\Delta V_F = V_F - V_F (25 \text{ °C}) = f(T_j); I_F = 24000 \text{ mA};$ all chips operated in parallel



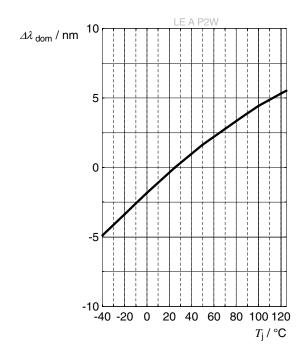
### **Relative Luminous Flux**<sup>4)</sup>

 $\Phi_v/\Phi_v(25 \text{ °C}) = f(T_j); I_F = 24000 \text{ mA};$ all chips operated in parallel



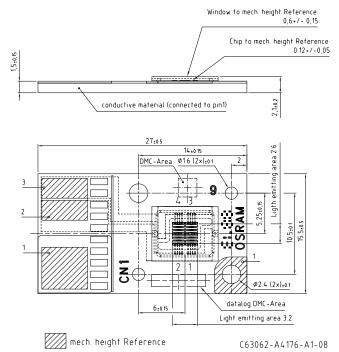
### **Dominant Wavelength**<sup>4)</sup>

 $\Delta\lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \ ^{\circ}C) = f(T_j); \ I_F = 24000 \ mA;$  all chips operated in parallel





## Dimensional Drawing <sup>8)</sup>

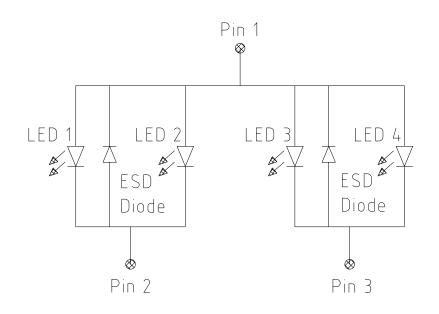


## **Further Information:**

Approximate Weight:	5,000.0 mg
Corrosion test:	Class: 3B Test condition: 40°C / 90 % RH / 15 ppm H <sub>2</sub> S / 14 days (stricter than IEC 60068-2-43)
ESD advice:	The device is protected by ESD device which is connected in parallel to the Chip.
Notes:	Package not suitable for any kind of wet cleaning or ultrasonic cleaning.
Connector:	Recommended connector: TARNG YU ENTERPRISE CO.,LTD / TA8051W- NR-02S-A / PO: 4510445465



### **Electrical Internal Circuit**

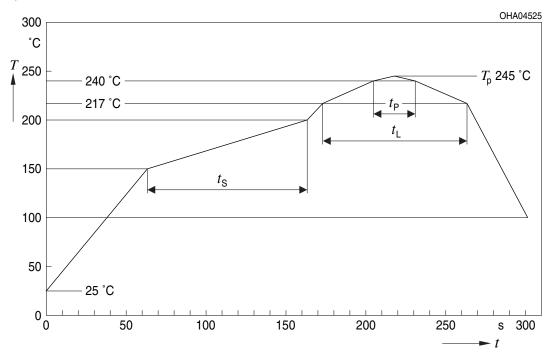


1: anode 2: cathode LED 1 and 2 3: cathode LED 3 and 4



### **Reflow Soldering Profile**

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



Profile Feature	Symbol Pl		Pb-Free (SnAgCu) Assembly		Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat <sup>*)</sup> 25 °C to 150 °C			2	3	K/s
Time t <sub>s</sub> T <sub>smin</sub> to T <sub>smax</sub>	t <sub>s</sub>	60	100	120	S
Ramp-up rate to peak <sup>*)</sup> $T_{smax}$ to $T_{p}$			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	t		80	100	S
Peak temperature	T <sub>P</sub>		245	260	°C
Time within 5 °C of the specified peak temperature $T_P$ - 5 K	t <sub>P</sub>	10	20	30	S
Ramp-down rate* T <sub>P</sub> to 100 °C			3	6	K/s
Time 25 °C to T <sub>P</sub>				480	S

All temperatures refer to the center of the package, measured on the top of the component

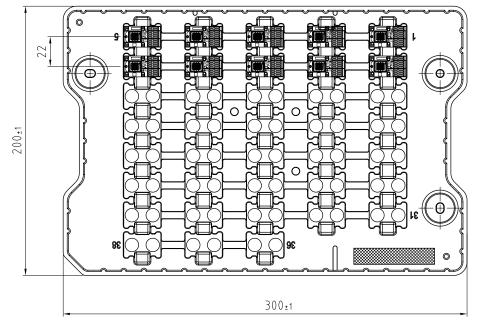
\* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

Discontinued



### LE A P2W

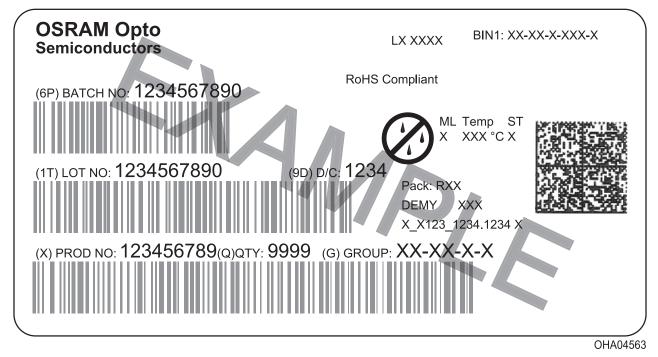
# Taping<sup>8)</sup>



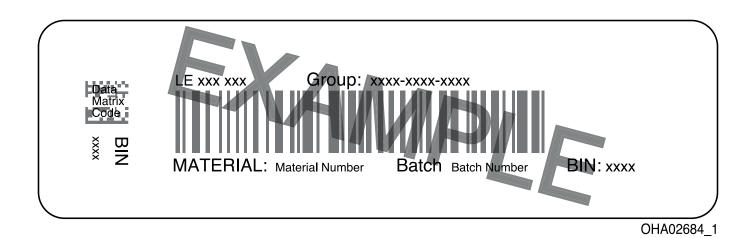
C63062-A4389-B10-01



### **Barcode-Product-Label (BPL)**



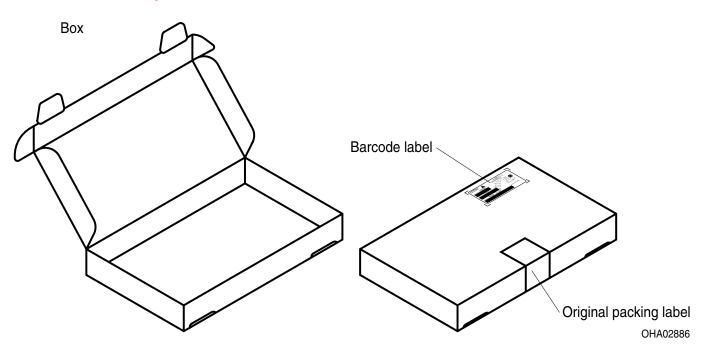
### **Barcode-Tray-Label (BTL)**



Discontinued



# Schematic Transportation Box <sup>8)</sup>

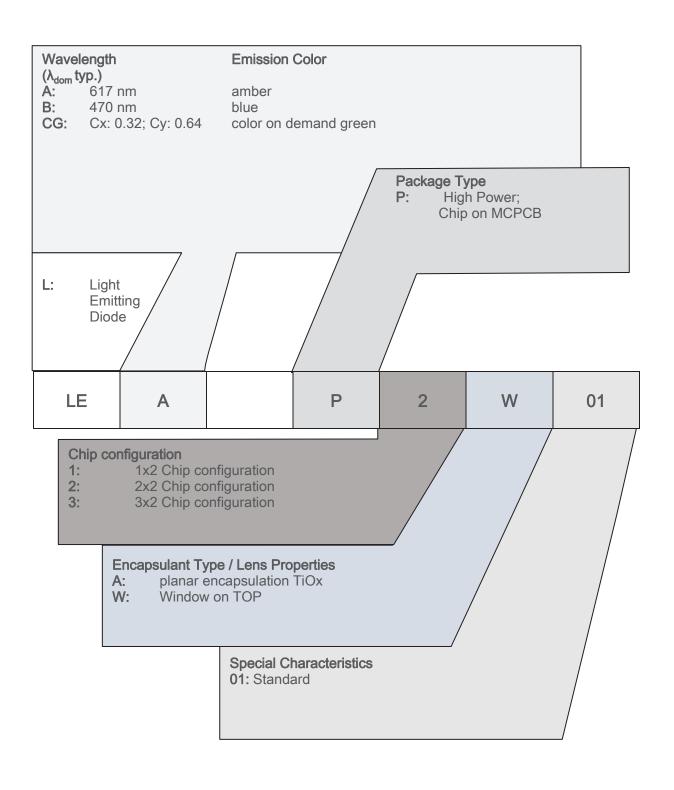


## **Dimensions of Transportation Box**

Width	Length	Height	
333 ± 5 mm	218 ±5 mm	28 ± 5 mm	
337 ± 5 mm	218 ±5 mm	63 ± 5 mm	



### **Type Designation System**





## Data Matrix Code Description

The Data Matrix Code bin information is Laser marked during testing Content: aaaa@bbbbb@cccc@ddddd@eeeee Data Matrix Code Type: ECC200

a = Luminous Flux (Phiv) [Im] or Radiant Flux (Phie) [W]	(example: 3306)
b = Forward Voltage (Vf) [V]	(example: 3.46)
c = Wavelength (Ldom) [nm]	(example: 618)
d = Color Coordinate Cx	(example: 0.321)
e = Color Coordinate Cy	(example: 0.641)
@: Seperator = Blank	



### Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



### Disclaimer

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

#### Packing

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### Glossary

- <sup>1)</sup> Brightness: Brightness values are measured during a pulse train of 100 ms with a pulse width of 250 µs and a frequencey of 1 kHz, with an internal reproducibility of +/- 8 % and an expanded uncertainty of +/- 11 % (acc. to GUM with a coverage factor of k = 3). The peak brightness is calculated according to the pulse duration and frequency.
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- <sup>3)</sup> **Wavelength:** The wavelength is measured during a pulse train of 100 ms with a pulse width of 250  $\mu$ s and a frequencey of 1 kHz, with an internal reproducibility of ± 0,5 nm and an expanded uncertainty of ± 1 nm (acc. to GUM with a coverage factor of k=3).
- <sup>4)</sup> Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- <sup>5)</sup> **Forward Voltage:** The forward voltage is measured during a pulse of typical 250 μs, with an internal reproducibility of +/- 0,05 V and an expanded uncertainty of +/- 0,1 V (acc. to GUM with a coverage factor of k=3).
- <sup>6)</sup> **Thermal Resistance:** Rth max is based on statistic values ( $6\sigma$ ).
- <sup>7)</sup> **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- <sup>8)</sup> **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



Revision History		
Version	Date	Change
1.9	2018-11-28	Ordering Information Characteristics Electro - Optical Characteristics (Diagrams) New Layout
1.10	2019-09-05	Тгау
1.11	2020-06-30	Not for new design
1.12	2020-10-13	Discontinued



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